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# Hyperfast Rectifier, 15 A FRED Pt<sup>®</sup>



TO-220 FullPAK 2L

PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub> 15 A						
VR	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.25 V					
t <sub>rr</sub> (typ.)	21 ns					
T <sub>J</sub> max.	175 °C					
Package	TO-220 FullPAK 2L					
Circuit configuration	Single					

#### **FEATURES**

- · Hyperfast soft recovery time
- · Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>BMS</sub>)
- True 2 pin package
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **DESCRIPTION / APPLICATIONS**

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V				
Average rectified forward current in DC	I <sub>F(AV)</sub>	T <sub>C</sub> = 94 °C	15	٨				
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_J = 25 \ ^{\circ}C$	160	A				
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C				

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 $^{\circ}$ C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-			
Forward voltage	VF	I <sub>F</sub> = 15 A	-	1.8	2.45	V		
	VF	I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	1.25	1.6			
		$V_{\rm R} = V_{\rm R}$ rated	-	0.01	15			
Reverse leakage current	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	20	200	μA		
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	12	-	pF		
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8	-	nH		

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DYNAMIC RECOVERY CHARACTERISTICS (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100$	A/ $\mu$ s, V <sub>R</sub> = 30 V	-	21	26		
Poverse recovery time	t <sub>rr</sub>	$I_F = 15 \text{ A}, \text{ d}I_F/\text{d}t = 10$	0 A/µs, V <sub>R</sub> = 30 V	-	25	36	ns	
Reverse recovery time	۲r	T <sub>J</sub> = 25 °C		-	29	-		
		T <sub>J</sub> = 125 °C	Ī	-	65	-		
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	l <sub>F</sub> = 15 A, dl <sub>F</sub> /dt = 200 A/µs,	-	3.9	-	A	
Feak recovery current		T <sub>J</sub> = 125 °C	$V_{\rm B} = 390 \text{ V}$	-	7.0	-		
Poweree receivery charge	0	T <sub>J</sub> = 25 °C		-	60	-	nC	
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	240	-	ne	
Reverse recovery time	t <sub>rr</sub>		I <sub>F</sub> = 15 A, dI <sub>F</sub> /dt = 800 A/μs,	-	42	-	ns	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 125 °C		-	21	-	А	
Reverse recovery charge	Q <sub>rr</sub>	V <sub>R</sub> = 390 V		-	480	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C		
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	3.7	4.3			
Thermal resistance, junction-to-ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70	°C/W		
Typical thermal resistance, case-to-heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-			
Weight			-	2	-	g		
Weight			-	0.07	-	oz.		
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style TO-220 FullPAK 2L	ETH1506FP					



### VS-ETH1506FP-M3

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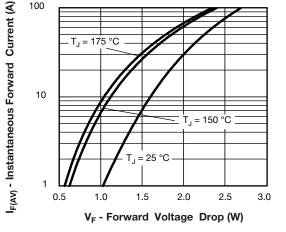


Fig. 1 - Typical Forward Voltage Drop Characteristics

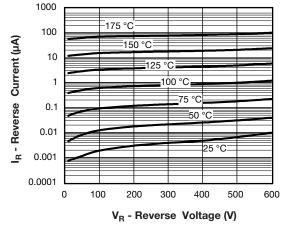


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

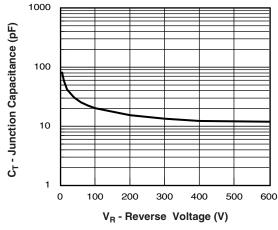


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

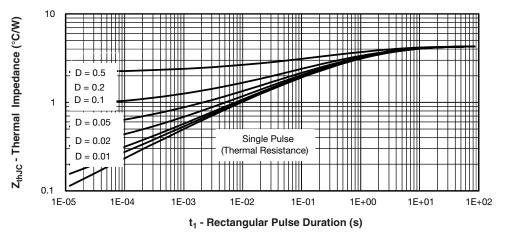


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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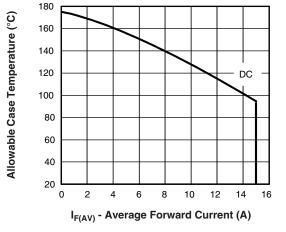
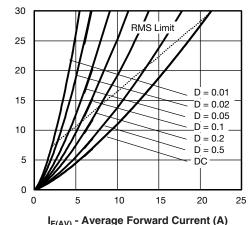


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current



Average Power Loss (W)

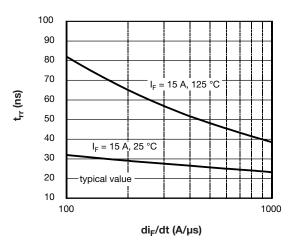
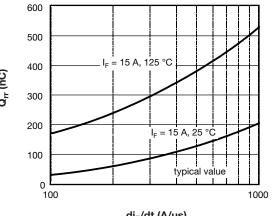


Fig. 7 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt



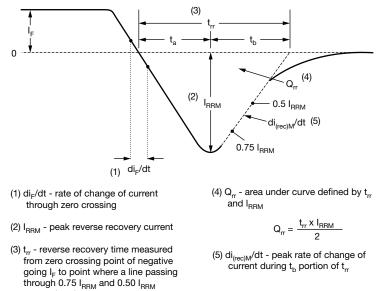


Fig. 9 - Reverse Recovery Waveform and Definitions

extrapolated to zero current.

Q<sub>rr</sub> (nC) di<sub>F</sub>/dt (A/µs) I<sub>F(AV)</sub> - Average Forward Current (A) Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt Fig. 6 - Forward Power Loss Characteristics

**VS-ETH1506FP-M3** 

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#### **ORDERING INFORMATION TABLE**

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Device code	vs-	Е	т	н	15	06	FP	-M3
				<u> </u>				
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)
	$\bigcirc$							
	1 -	- Visl	nay Serr	niconduo	ctors pr	oduct		
	2 -	- Circ	cuit cont	figuratio	n:			
		E =	single					
	3 -	• T=	TO-220	)				
	4 -	- H=	hyperfa	ast recov	very tim	е		
	5 -	- Cur	rent coo	de: 15 =	15 A			
	6 -	- Vol	tage coo	de: 06 =	600 V			
	7 -	· FP	= TO-22	20 FullP	AK 2L			
	8 -	- Env	rironmer	ntal digit				
		-M3	3 = halog	gen-free	, RoHS	-compli	ant, and	d termir

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-ETH1506FP-M3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96157				
Part marking information	www.vishay.com/doc?95392				

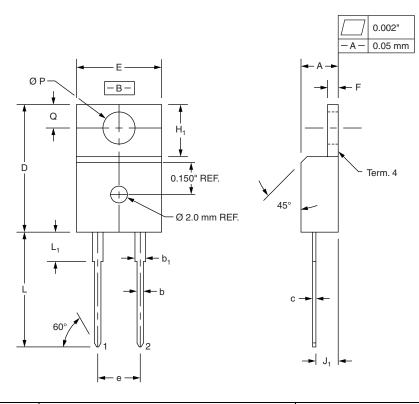




Din TO 220

## True 2 Pin TO-220

#### **DIMENSIONS** in millimeters and inches



SYMBOL -	MILLIN	IETERS	INCHES		
	MIN.	MAX.	MIN.	MAX.	
A	4.32	4.57	0.170	0.180	
b	0.71	0.91	0.028	0.036	
b <sub>1</sub>	1.15	1.39	0.045	0.055	
с	0.36	0.53	0.014	0.021	
D	14.99	15.49	0.590	0.610	
E	10.04	10.41	0.395	0.410	
e	5.08	BSC	0.200 BSC		
F	1.22	1.37	0.048	0.054	
H <sub>1</sub>	5.97	6.47	0.235	0.255	
J <sub>1</sub>	2.54	2.79	0.100	0.110	
L	13.47	13.97	0.530	0.550	
L <sub>1</sub> <sup>(1)</sup>	3.31	3.81	0.130	0.150	
Ø P	3.79	3.88	0.149	0.153	
Q	2.60	2.84	0.102	0.112	

#### Notes

 $^{\left(1\right)}$  Lead dimension and finish uncontrolled in  $L_{1}$ 

• These dimensions are within allowable dimensions of JEDEC TO-220AB rev. J outline dated 3-24-87

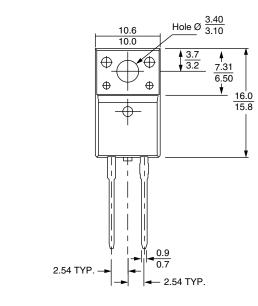
Controling dimension: Inch

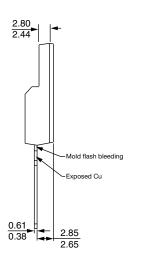


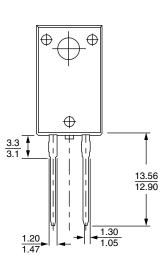
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## 2L TO-220 FullPAK

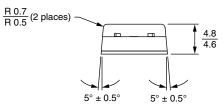
#### **DIMENSIONS** in millimeters







Bottom view





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